QW-B0039

CDSH3-21-G Voltage: 200 Volts Current: 200 mA RoHS Device

Features

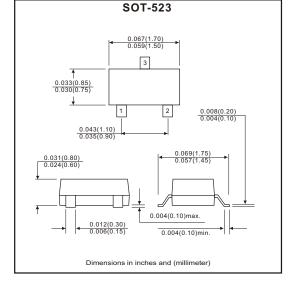
- -Fast switching speed.
- -For general purpose switching applications.
- -High conductance.

Mechanical data

- -Case: SOT-523, molded plastic.
- -Terminals: Solder plated, solderable per MIL-STD-202E, method 208C.
- -Weight: 0.002 grams approx.

Circuit Diagram





Maximum Ratings (at TA=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Peak repetitive peak reverse voltage	Vrrm		
Working peak reverse voltage	Vrwm	200	V
DC blocking voltage	Vr		
Forward continuous current	Іғм	400	mA
Averaged rectified output current	lo	200	mA
Non-repetitive Peak forward surge current @TP=1.0µS @TP=1.0S	Ifsm	2.5 0.5	А
Power dissipation	PD	150	mW
Thermal resistance, junction to ambient air	Reja	833	°C/W
Operating junction temperature	TJ	150	°C
Storage temperature range	Тѕтс	-65 to +150	°C

Electrical Ratings @TA=25°C unless otherwise noted.

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Reverse breakdown voltage	Vbr	IR=100µA	200			V
Forward voltage	V _{F1}	I⊧=100mA			1	V
	VF2	I⊧=200mA			1.25	V
Reverse current	Ir	V _R =200V			100	nA
Capacitance between terminals	Ст	V _R =0V, f=1MHz			5	рF
Reverse recovery time	Trr	I⊧=I₨=30mA, I₨=0.1I₨, ₨=100Ω			50	nS









Rating and Characteristic Curves (CDSH3-21-G)

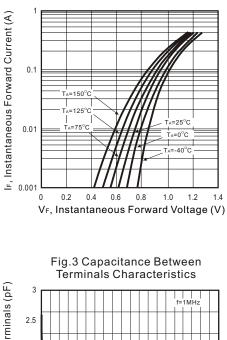


Fig.1 Forward Characteristics

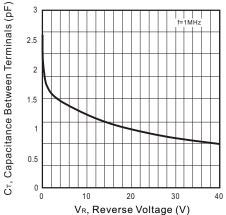


Fig.2 Reverse Characteristics

X | X \ X

SMD Diodes Specialist

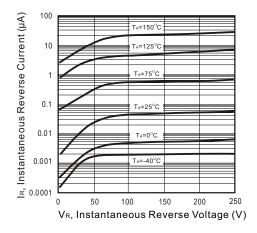


Fig.4 Power Derating Curve

